

TOSHIBA PHOTOCOUPLER PHOTO-RELAY

TLP224G, TLP224G-2

MODEMS

PBX

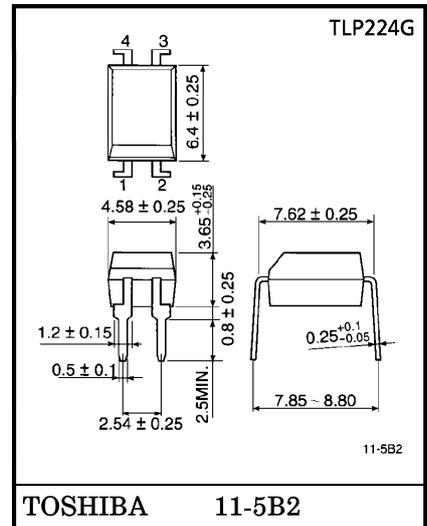
TELECOMMUNICATIONS

The TOSHIBA TLP224G series consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a 4pin DIP (DIP4), which is suitable for equipment for high tech communications, including modems.

The TLP224G series complies with FCC part 68 rules with current limiting function.

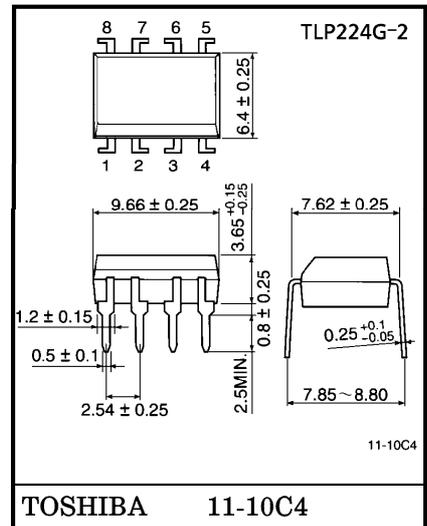
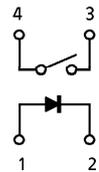
- TLP224G : 4 PIN DIP, 1 Channel Type (1 Form A)
- TLP224G-2 : 8 PIN DIP, 2 Channel Type (2 Form A)
- Peak Off-State Voltage : 350 V (min)
- Trigger LED Current : 3 mA (max)
- On-State Current : 120 mA (max)
- Load Current Limiting : 150 mA~300 mA (t = 5 ms)
- On-State Resistance : 35 Ω (max)
- Isolation Voltage : 2500 Vrms (min)
- UL Recognized : UL1577, File No. E67349

Unit in mm



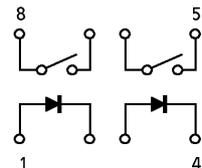
Weight : 0.26 g

1 Form A



Weight : 0.54 g

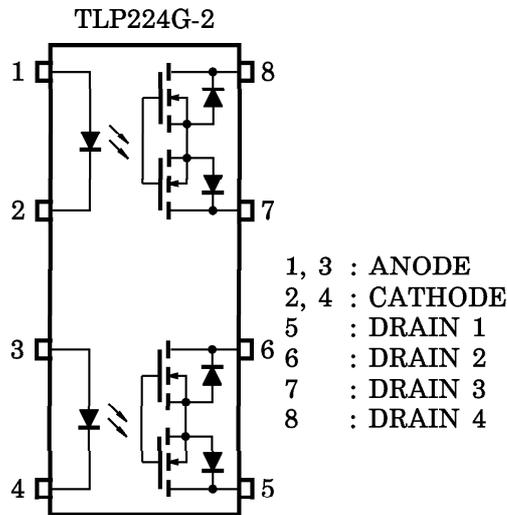
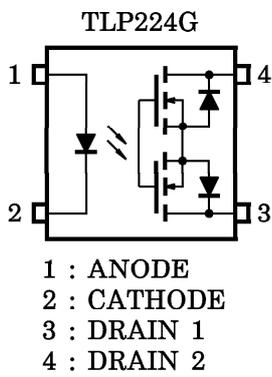
2 Form A



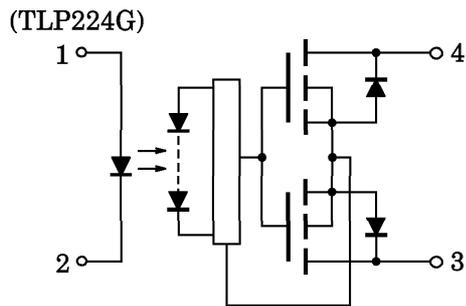
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PIN CONFIGURATION (TOP VIEW)



INTERNAL CIRCUIT



980910EBC2'

- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current	I _F	50	mA
	Forward Current Derating (Ta ≥ 25°C)	ΔI _F / °C	-0.5	mA / °C
	Peak Forward Current (100 μs pulse, 100 pps)	I _{FP}	1	A
	Reverse Voltage	V _R	6	V
	Junction Temperature	T _j	125	°C
DETECTOR	Off-State Output Terminal Voltage	V _{OFF}	350	V
	On-State Current (Note 1)	I _{ON}	120	mA
	On-State Current Derating (Ta ≥ 25°C) (Note 1)	ΔI _{ON} / °C	-1.2	mA / °C
	Junction Temperature	T _j	125	°C
Storage Temperature Range		T _{stg}	-55~125	°C
Operating Temperature Range		T _{opr}	-40~85	°C
Lead Soldering Temperature (10 s)		T _{sol}	260	°C
Isolation Voltage (AC, 1 min., R.H. ≤ 60%) (Note 2)		BV _S	2500	V _{rms}

(Note 1) : Two channles operating simultaneously.

(Note 2) : Device considered a two-terminal device : LED side pins shoted together, and Detector side pins shored together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Voltage	V _{DD}	—	—	280	V
Forward Current	I _F	5	7.5	25	mA
On-State Current	I _{ON}	—	—	100	mA
Operating Temperature	T _{opr}	-20	—	65	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
LED	Forward Voltage	V_F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	I_R	$V_R = 6 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Off-State Current	I_{OFF}	$V_{OFF} = 350 \text{ V}$	—	—	1	μA
	Capacitance	C_{OFF}	$V = 0, f = 1 \text{ MHz}$	—	40	—	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Trigger LED Current	I_{FT}	$I_{ON} = 120 \text{ mA}$	—	1	3	mA
Load Current Limiting	I_{LIM}	$I_F = 5 \text{ mA}, V_{DD} = 5 \text{ V}, t = 5 \text{ ms}$	150	—	300	mA
On-State Resistance	R_{ON}	$I_{ON} = 120 \text{ mA}, I_F = 5 \text{ mA}$	—	22	35	Ω

ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Capacitance Input to Output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$V_S = 500 \text{ V}, R.H. \leq 60\%$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1 minute	2500	—	—	V_{rms}
		AC, 1 second (in oil)	—	5000	—	
		DC, 1 minute (in oil)	—	5000	—	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Turn-on Time	t_{ON}	$R_L = 200 \Omega$ (Note 1)	—	—	1	ms
Turn-off Time	t_{OFF}	$V_{CC} = 20 \text{ V}, I_F = 5 \text{ mA}$	—	—	1	

(Note 1) : SWITCHING TIME TEST CIRCUIT

